

# DALLAS

SEMICONDUCTOR

## DS14285/DS14287

### Real Time Clock with NV RAM Control

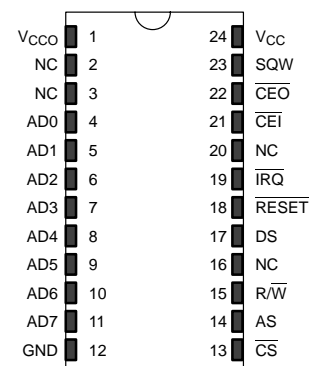
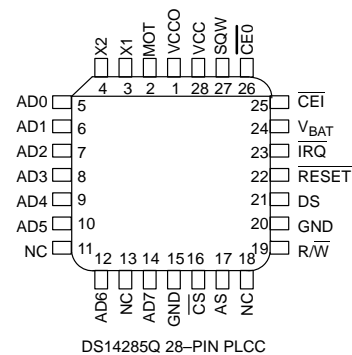
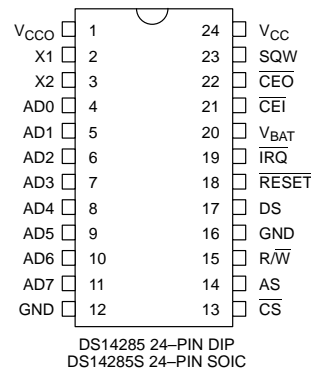
#### FEATURES

- Direct replacement for IBM AT computer clock/calendar
- Functionally compatible with the DS1285/DS1287
- Available as chip (DS14285, DS14285S, or DS14285Q) or stand-alone module with embedded lithium battery and crystal (DS14287)
- Automatic backup supply and write protection to make external SRAM nonvolatile
- Counts seconds, minutes, hours, days, day of the week, date, month, and year with leap year compensation valid up to 2100
- Binary or BCD representation of time, calendar, and alarm
- 12- or 24-hour clock with AM and PM in 12-hour mode
- Daylight Savings Time option
- Multiplex bus for pin efficiency
- Interfaced with software as 128 RAM locations
  - 14 bytes of clock and control registers
  - 114 bytes of general purpose RAM
- Programmable square wave output signal
- Bus-compatible interrupt signals ( $\overline{\text{IRQ}}$ )
- Three interrupts are separately software-maskable and testable
  - Time-of-day alarm once/second to once/day
  - Periodic rates from 122  $\mu\text{s}$  to 500 ms
  - End of clock update cycle
- Optional industrial temperature version available  
DS14285 DIP, SOIC, and PLCC

#### ORDERING INFORMATION

DS14285	RTC Chip; 24-pin DIP
DS14285S	RTC Chip; 24-pin SOIC
DS14285Q	RTC Chip; 28-pin PLCC
DS14287	RTC Module; 24-pin DIP

#### PIN ASSIGNMENT



**PIN DESCRIPTION**

AD0–AD7	– Multiplexed Address/Data Bus
NC	– No Connection
MOT	– Bus Type Select (DS14285Q only)
$\overline{\text{CS}}$	– Chip Select
AS	– Address Strobe
R/W	– Read/Write Input
DS	– Data Strobe
RESET	– Reset Input
$\overline{\text{IRQ}}$	– Interrupt Request Output
SQW	– Square Wave Output
V <sub>CC</sub>	– +5 Volt Supply
GND	– Ground
V <sub>CCO</sub>	– RAM Power Supply Output
$\overline{\text{CEI}}$	– RAM Chip Enable In
$\overline{\text{CEO}}$	– RAM Chip Enable Out
X1, X2	– 32.768 KHz Crystal Connections
V <sub>BAT</sub>	– +3 Volt Battery Input

**DESCRIPTION**

The DS14285/DS14287 Real Time Clock with NVRAM Control provides the industry standard DS1287 clock function with the additional feature of providing nonvolatile control for an external SRAM. Functions include a nonvolatile time-of-day clock, alarm, one-hundred year calendar, programmable interrupt, square wave generator, and 114 bytes of nonvolatile static RAM. For the DS14287 a lithium energy source, quartz crystal, and write-protection circuitry are contained within a 24-pin dual-in-line package. The DS14285 requires an external quartz crystal connected to the X1 and X2 pins as well as an external energy source connected to the V<sub>BAT</sub> pin.

A standard 32,768 KHz quartz crystal can be directly connected to the DS14285 via pins 1 and 2 (X1, X2). The crystal selected for use should have a specified load capacitance (C<sub>L</sub>) of 6 pF. For more information on crystal selection and crystal layout considerations, please consult Application Note 58, "Crystal Considerations with Dallas Real Time Clocks".

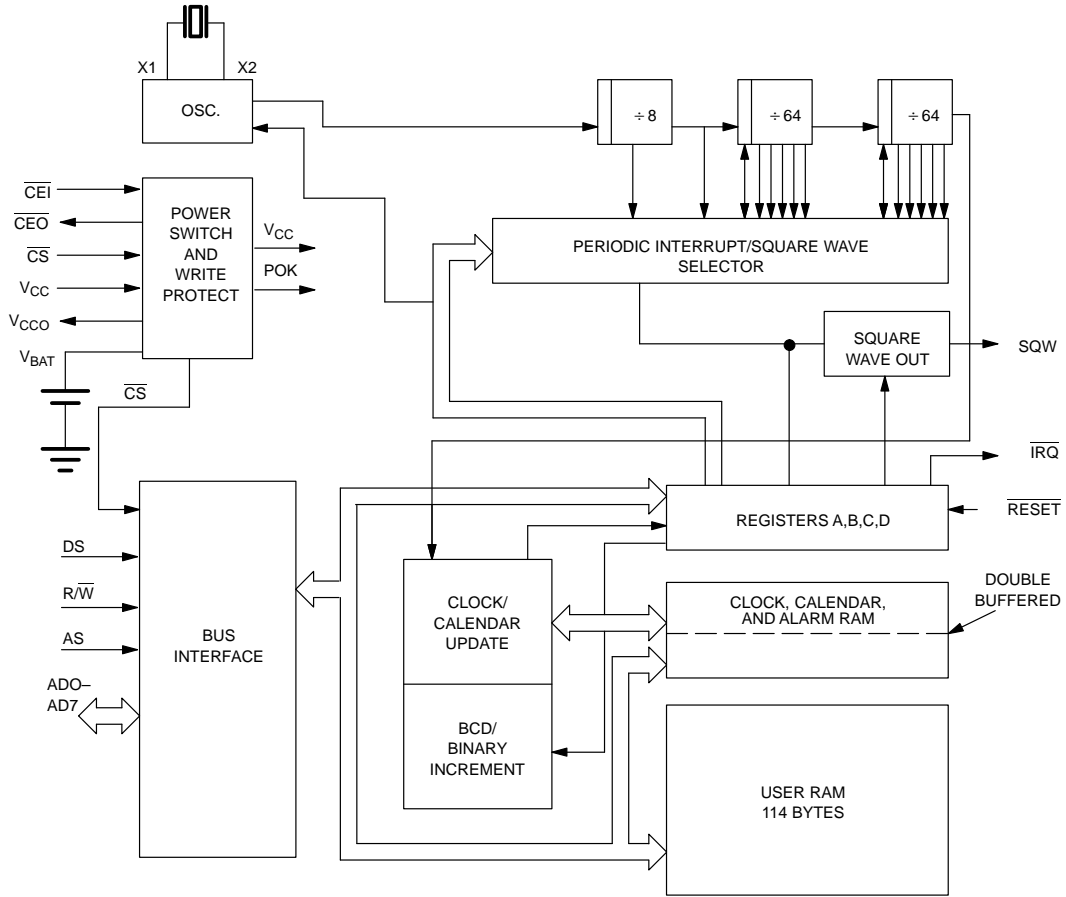
The DS14285/DS14287 uses its backup energy source and battery-backup controller to make a standard CMOS static RAM nonvolatile during power-fail conditions. During power fail, the DS14285/DS14287 automatically write protects the external SRAM and provides a V<sub>CC</sub> output sourced from its internal battery.

For the DS14287 the internal lithium cell is electrically isolated from the clock and memory when shipped from the factory. This isolation is removed after the first application of V<sub>CC</sub> allowing the lithium cell to provide data retention to the clock, internal RAM, V<sub>CCO</sub> and  $\overline{\text{CEO}}$  on subsequent power-downs. Care must be taken after this isolation has been broken to avoid inadvertently discharging the lithium cell through the V<sub>CCO</sub> and  $\overline{\text{CEO}}$  pins.

**OPERATION**

The block diagram in Figure 1 shows the pin connections with the major internal functions of the DS14285/DS14287. The following paragraphs describe the function of each pin.

DS14285/DS14287 BLOCK DIAGRAM Figure 1



## POWER-DOWN/POWER-UP CONSIDERATIONS

The Real Time Clock function will continue to operate and all of the RAM, time, calendar, and alarm memory locations remain nonvolatile regardless of the level of the  $V_{CC}$  input. When  $V_{CC}$  is applied to the DS14285/DS14287 and reaches a level of greater than 4.25 volts (typical), the device becomes accessible after 200 ms, provided that the oscillator is running and the oscillator countdown chain is not in reset (see Register A). This time period allows the system to stabilize after power is applied. When  $V_{CC}$  falls below 4.25 volts (typical), the chip select input is internally forced to an inactive level regardless of the value of  $\overline{CS}$  at the input pin. The DS14285/DS14287 is, therefore, write-protected. When the DS14285/DS14287 is in a write-protected state, all inputs are ignored and all outputs are in a high impedance state. When  $V_{CC}$  falls below a level of approximately 3 volts, the external  $V_{CC}$  supply is switched off and an internal lithium energy source supplies power to the Real Time Clock and the RAM memory.

An external SRAM can be made nonvolatile by using the  $V_{CCO}$  and SRAM chip enable pins (see Figure 2). Non-volatile control of the external SRAM is analogous to that of the real-time clock registers. When  $V_{CC}$  slews down during a power fail,  $\overline{CEO}$  is driven to an inactive level regardless  $\overline{CEI}$ . This write protection occurs when  $V_{CC}$  is less than 4.25 volts (typical).

During power up, when  $V_{CC}$  reaches a level of greater than 4.25 volts (typical),  $\overline{CEO}$  will reflect  $\overline{CEI}$  after 200 ms. During power-valid operation, the  $\overline{CEI}$  input is passed to the CEO output with a propagation delay of less than 10 ns.

When  $V_{CC}$  is above a level of approximately 3V, the external SRAM will be powered by  $V_{CC}$  through the  $V_{CCO}$  pin. When  $V_{CC}$  is below a level of approximately 3V, the external SRAM will be powered by the internal

lithium cell through the  $V_{CCO}$  pin. An internal comparator and switch determine whether  $V_{CCO}$  is powered by  $V_{CC}$  or the internal lithium cell.

When the device is in battery backup mode, the energy source connected to the  $V_{BAT}$  pin in the case of the DS14285, or the internal lithium cell in the case of the DS14287 can power an external SRAM for an extended period of time. The amount of time that the lithium cell can supply power to the external SRAM is a function of the data retention current of the SRAM. The capacity of the lithium cell that is encapsulated within the DS14287 module is 130 mAh. If a SRAM with a data retention current of less than 1  $\mu$ A is used and the oscillator current is 300 nA (typical), the cumulative data retention time is calculated at more than 11 years.

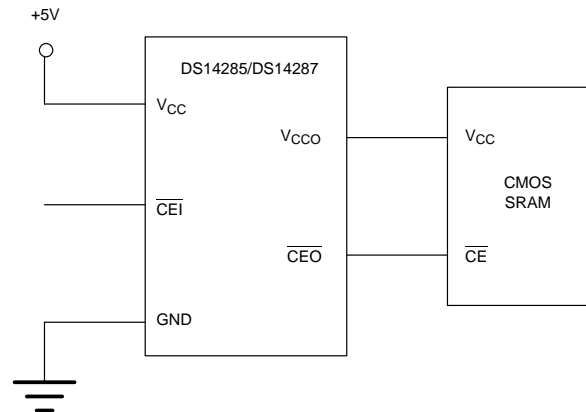
## SIGNAL DESCRIPTIONS

GND,  $V_{CC}$  – DC power is provided to the device on these pins.  $V_{CC}$  is the +5 volt input. When 5 volts are applied within normal limits, the device is fully accessible and data can be written and read. When  $V_{CC}$  is below 4.25 volts typical, reads and writes are inhibited. However, the timekeeping function continues unaffected by the lower input voltage. As  $V_{CC}$  falls below 3 volts typical, the RAM and timekeeper are switched over to an internal lithium energy source. The timekeeping function maintains an accuracy of  $\pm 1$  minute per month at 25°C regardless of the voltage input on the  $V_{CC}$  pin.

SQW (Square Wave Output) – The SQW pin can output a signal from one of 13 taps provided by the 15 internal divider stages of the Real Time Clock. The frequency of the SQW pin can be changed by programming Register A as shown in Table 1. The SQW signal can be turned on and off using the SQWE bit in Register B. The SQW signal is not available when  $V_{CC}$  is less than 4.25 volts typical.

**PERIODIC INTERRUPT RATE AND SQUARE WAVE OUTPUT FREQUENCY** Table 1

SELECT BITS REGISTER A				$t_{PI}$ PERIODIC INTERRUPT RATE	SQW OUTPUT FREQUENCY
RS3	RS2	RS1	RS0		
0	0	0	0	None	None
0	0	0	1	3.90625 ms	256 Hz
0	0	1	0	7.8125 ms	128 Hz
0	0	1	1	122.070 $\mu$ s	8.192 kHz
0	1	0	0	244.141 $\mu$ s	4.096 kHz
0	1	0	1	488.281 $\mu$ s	2.048 kHz
0	1	1	0	976.5625 $\mu$ s	1.024 kHz
0	1	1	1	1.953125 ms	512 Hz
1	0	0	0	3.90625 ms	256 Hz
1	0	0	1	7.8125 ms	128 Hz
1	0	1	0	15.625 ms	64 Hz
1	0	1	1	31.25 ms	32 Hz
1	1	0	0	62.5 ms	16 Hz
1	1	0	1	125 ms	8 Hz
1	1	1	0	250 ms	4 Hz
1	1	1	1	500 ms	2 Hz

**EXTERNAL SRAM INTERFACE TO THE DS14285/DS14287 RTC** Figure 2

**AD0–AD7 (Multiplexed Bidirectional Address/Data Bus)** – Multiplexed buses save pins because address information and data information time share the same signal paths. The addresses are present during the first portion of the bus cycle and the same pins and signal paths are used for data in the second portion of the cycle. Address/data multiplexing does not slow the access time of the DS14285/DS14287 since the bus change from address to data occurs during the internal RAM access time. Addresses must be valid prior to the falling edge of AS/ALE, at which time the DS14285/DS14287 latches the address from AD0 to AD6. Valid write data must be present and held stable during the latter portion of the DS or  $\overline{WR}$  pulses. In a read cycle the DS14285/DS14287 outputs 8 bits of data during the latter portion of the DS or  $\overline{RD}$  pulses. The read cycle is terminated and the bus returns to a high impedance state as DS transitions low in the case of Motorola timing or as  $\overline{RD}$  transitions high in the case of Intel timing.

**MOT (Mode Select)** – The MOT pin offers the flexibility to choose between to bus types. When connected to  $V_{CC}$ , Motorola bus timing is selected. When connected to GND or left disconnected, Intel bus timing is selected. The pin has an internal pull-down resistance of approximately 20 k $\Omega$ . This pin is on the DS14285Q only.

**AS (Address Strobe Input)** – A positive going address strobe pulse serves to demultiplex the bus. The falling edge of AS/ALE causes the address to be latched within the DS14285/DS14287.

**DS (Data Strobe or Read Input)** – For the DS14285Q the DS/ $\overline{RD}$  pin has two modes of operation depending on the level of the MOT pin. When the MOT pin is connected to  $V_{CC}$ , Motorola bus timing is selected. In this mode DS is a positive pulse during the latter portion of the bus cycle and is called Data Strobe. During read cycles, DS signifies the time that the DS14285Q is to drive the bidirectional bus. In write cycles the trailing edge of DS causes the DS14285Q to latch the written data. When the MOT pin is connected to GND, Intel bus timing is selected. In this mode the DS pin is called Read( $\overline{RD}$ ).  $\overline{RD}$  identifies the time period when the DS14285Q drives the bus with read data. The  $\overline{RD}$  signal is the same definition as the Output Enable ( $\overline{OE}$ ) signal on a typical memory.

The DS14285, DS14285S and DS14287 do not have a MOT pin and therefore operate only in Intel bus timing mode.

**$\overline{R/\overline{W}}$  (Read/Write Input)** – The  $\overline{R/\overline{W}}$  pin also has two modes of operation. When the MOT pin is connected to  $V_{CC}$  for Motorola timing,  $\overline{R/\overline{W}}$  is at a level which indicates whether the current cycle is a read or write. A read cycle is indicated with a high level on  $\overline{R/\overline{W}}$  while DS is high. A write cycle is indicated when  $\overline{R/\overline{W}}$  is low during DS.

When the MOT pin is connected to GND for Intel timing, the  $\overline{R/\overline{W}}$  signal is an active low signal called  $\overline{WR}$ . In this mode the  $\overline{R/\overline{W}}$  pin has the same meaning as the Write Enable signal ( $\overline{WE}$ ) on generic RAMs.

**$\overline{CS}$  (Chip Select Input)** – The Chip Select signal must be asserted low for a bus cycle in the DS14285/DS14287 to be accessed.  $\overline{CS}$  must be kept in the active state during DS for Motorola timing and during  $\overline{RD}$  and  $\overline{WR}$  for Intel timing. Bus cycles which take place without asserting  $\overline{CS}$  will latch addresses but no access will occur. When  $V_{CC}$  is below 4.25 volts, the DS14285/DS14287 internally inhibits access cycles by internally disabling the  $\overline{CS}$  input. This action protects both the real time clock data and RAM data during power outages.

**$\overline{IRQ}$  (Interrupt Request Output)** – The  $\overline{IRQ}$  pin is an active low output of the DS14285/DS14287 that can be used as an interrupt input to a processor. The  $\overline{IRQ}$  output remains low as long as the status bit causing the interrupt is present and the corresponding interrupt-enable bit is set. To clear the  $\overline{IRQ}$  pin the processor program normally reads the C register. The  $\overline{RESET}$  pin also clears pending interrupts.

When no interrupt conditions are present, the  $\overline{IRQ}$  level is in the high impedance state. Multiple interrupting devices can be connected to an  $\overline{IRQ}$  bus. The  $\overline{IRQ}$  bus is an open drain output and requires an external pull-up resistor.

**$\overline{RESET}$  (Reset Input)** – The  $\overline{RESET}$  pin has no effect on the clock, calendar, or RAM. On power-up the  $\overline{RESET}$  pin can be held low for a time in order to allow the power supply to stabilize. The amount of time that  $\overline{RESET}$  is held low is dependent on the application. However, if  $\overline{RESET}$  is used on power-up, the time  $\overline{RESET}$  is low should exceed 200 ms to make sure that the internal timer that controls the DS14285/DS14287 on power-up has timed out. When  $\overline{RESET}$  is low and  $V_{CC}$  is above 4.25 volts, the following occurs:

- A. Periodic Interrupt Enable (PEI) bit is cleared to zero.

- B. Alarm Interrupt Enable (AIE) bit is cleared to zero.
- C. Update Ended Interrupt Flag (UF) bit is cleared to zero.
- D. Interrupt Request Status Flag (IRQF) bit is cleared to zero.
- E. Periodic Interrupt Flag (PF) bit is cleared to zero.
- F. The device is not accessible until  $\overline{\text{RESET}}$  is returned high.
- G. Alarm Interrupt Flag (AF) bit is cleared to zero.
- H.  $\overline{\text{IRQ}}$  pin is in the high impedance state.
- I. Square Wave Output Enable ( $\overline{\text{SQWE}}$ ) bit is cleared to zero.
- J. Update Ended Interrupt Enable (UIE) is cleared to zero.
- K.  $\overline{\text{CEO}}$  is driven high.

In a typical application  $\overline{\text{RESET}}$  can be connected to  $V_{\text{CC}}$ . This connection will allow the DS14287 to go in and out of power fail without affecting any of the control registers.

**$\overline{\text{CEI}}$  (External RAM Chip Enable Input, active low)** –  $\overline{\text{CEI}}$  should be driven low to enable the external RAM.  $\overline{\text{CEI}}$  is internally pulled up with a 50k $\Omega$  resistor.

**$\overline{\text{CEO}}$  (External RAM Chp Enable Output, active low)** – When  $V_{\text{CC}}$  is greater than 4.25 volts (typical),  $\overline{\text{CEO}}$  will reflect  $\overline{\text{CEI}}$  provided the  $\overline{\text{RESET}}$  is at a logic high. When  $V_{\text{CC}}$  is less than 4.25 volts (typical),  $\overline{\text{CEO}}$  will be forced to an inactive level regardless of  $\overline{\text{CEI}}$ .

**$V_{\text{CCO}}$  (External RAM Power Supply Output)** –  $V_{\text{CCO}}$  provides the higher of  $V_{\text{CC}}$  or  $V_{\text{BAT}}$  through an internal switch to power an external RAM.

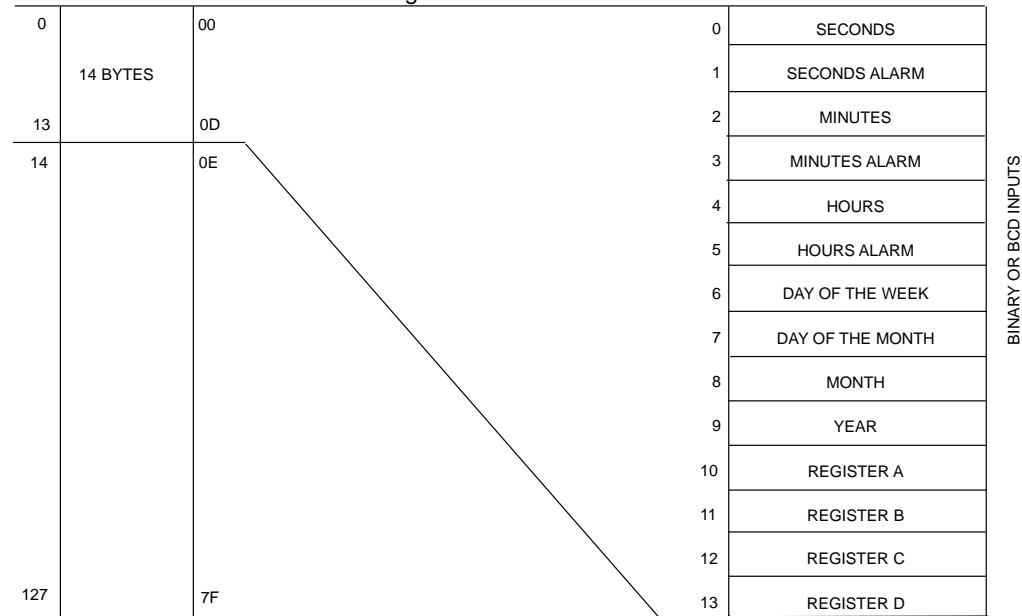
**ADDRESS MAP**

The address map of the DS14285/DS14287 is shown in Figure 3. The address map consists of 114 bytes of user RAM, 10 bytes of RAM that contain the RTC time, calendar, and alarm data, and four bytes which are used for control and status. All 128 bytes can be directly written or read except for the following:

1. Registers C and D are read-only.
2. Bit 7 of Register A is read-only.
3. The high order bit of the seconds byte is read-only.

The contents of four registers (A,B,C, and D) are described in the “Registers” section.

**DS14285/DS14287 ADDRESS MAP Figure 3**



**TIME, CALENDAR AND ALARM LOCATIONS**

The time and calendar information is obtained by reading the appropriate memory bytes. The time, calendar, and alarm are set or initialized by writing the appropriate RAM bytes. The contents of the ten time, calendar, and alarm bytes can be either Binary or Binary-Coded Decimal (BCD) format. Before writing the internal time, calendar, and alarm registers, the SET bit in Register B should be written to a logic one to prevent updates from occurring while access is being attempted. In addition to writing the ten time, calendar, and alarm registers in a selected format (binary or BCD), the data mode bit (DM) of Register B must be set to the appropriate logic level. All ten time, calendar, and alarm bytes must use the same data mode. The set bit in Register B should be cleared after the data mode bit has been written to allow the real time clock to update the time and calendar bytes. Once initialized, the real time clock makes all updates in the selected mode. The data mode cannot be changed without reinitializing the ten data bytes. Table 2 shows the binary and BCD formats of the ten time, calendar, and alarm locations. The 24–12 bit cannot be changed without reinitializing the hour locations. When the 12-hour format is selected, the high order bit of the hours byte represents PM when it is a logic one.

The time, calendar, and alarm bytes are always accessible because they are double buffered. Once per second the ten bytes are advanced by one second and checked for an alarm condition. If a read of the time and calendar data occurs during an update, a problem exists where seconds, minutes, hours, etc. may not correlate. The probability of reading incorrect time and calendar data is low. Several methods of avoiding any possible incorrect time and calendar reads are covered later in this text.

The three alarm bytes can be used in two ways. First, when the alarm time is written in the appropriate hours, minutes, and seconds alarm locations, the alarm interrupt is initiated at the specified time each day if the alarm enable bit is high. The second use condition is to insert a “don’t care” state in one or more of the three alarm bytes. The “don’t care” code is any hexadecimal value from C0 to FF. The two most significant bits of each byte set the “don’t care” condition when at logic 1. An alarm will be generated each hour when the “don’t care” bits are set in the hours byte. Similarly, an alarm is generated every minute with “don’t care” codes in the hours and minute alarm bytes. The “don’t care” codes in all three alarm bytes create an interrupt every second.

**TIME, CALENDAR AND ALARM DATA MODES** Table 2

ADDRESS LOCATION	FUNCTION	DECIMAL RANGE	RANGE	
			BINARY DATA MODE	BCD DATA MODE
0	Seconds	0–59	00–3B	00–59
1	Seconds Alarm	0–59	00–3B	00–59
2	Minutes	0–59	00–3B	00–59
3	Minutes Alarm	0–59	00–3B	00–59
4	Hours-12-hr Mode	1–12	01–0C AM, 81–8C PM	01–12AM,81–92PM
	Hours-24-hr Mode	0–23	00–17	00–23
5	Hours Alarm–12-hr	1–12	01–0C AM, 81–8C PM	01–12AM,81–92PM
	Hours Alarm–24-hr	0–23	00–17	00–23
6	Day of the Week Sunday = 1	1–7	01–07	01–07
7	Date of the Month	1–31	01–1F	01–31
8	Month	1–12	01–0C	01–12
9	Year	0–99	00–63	00–99



### NONVOLATILE RAM

The 114 general purpose nonvolatile RAM bytes are not dedicated to any special function within the DS14285/DS14287. They can be used by the processor program as nonvolatile memory and are fully available during the update cycle.

The DS14285/DS14287 can also provide additional nonvolatile RAM. This is accomplished through the use of its internal lithium cell in the case of the DS14287 (or the energy source connected to the  $V_{BAT}$  pin in the case of the DS14285) and battery-backup controller to make a standard CMOS SRAM nonvolatile during power-fail conditions. During power fail, the DS14285/DS14287 automatically write protects the external SRAM and provides a  $V_{CC}$  output sourced from the internal lithium cell. The interface between the DS14285/DS14287 and an external SRAM is illustrated in Figure 2.

### INTERRUPTS

The RTC plus RAM includes three separate, fully automatic sources of interrupt for a processor. The alarm interrupt can be programmed to occur at rates from once per second to once per day. The periodic interrupt can be selected for rates from 500 ms to 122  $\mu$ s. The update-ended interrupt can be used to indicate to the program that an update cycle is complete. Each of these independent interrupt conditions is described in greater detail in other sections of this text.

The processor program can select which interrupts, if any, are going to be used. Three bits in Register B enable the interrupts. Writing a logic 1 to an interrupt-enable bit permits that interrupt to be initiated when the event occurs. A zero in an interrupt-enable bit prohibits the  $\overline{IRQ}$  pin from being asserted from that interrupt condition. If an interrupt flag is already set when an interrupt is enabled,  $\overline{IRQ}$  is immediately set at an active level, although the interrupt initiating the event may have occurred much earlier. As a result, there are cases where the program should clear such earlier initiated interrupts before first enabling new interrupts.

When an interrupt event occurs, the relating flag bit is set to logic 1 in Register C. These flag bits are set independent of the state of the corresponding enable bit in Register B. The flag bit can be used in a polling mode without enabling the corresponding enable bits. The interrupt flag bit is a status bit which software can interrogate as necessary. When a flag is set, an indica-

tion is given to software that an interrupt event has occurred since the flag bit was last read; however, care should be taken when using the flag bits as they are cleared each time Register C is read. Double latching is included with Register C so that bits which are set remain stable throughout the read cycle. All bits which are set (high) are cleared when read and new interrupts which are pending during the read cycle are held until after the cycle is completed. One, two, or three bits can be set when reading Register C. Each utilized flag bit should be examined when read to ensure that no interrupts are lost.

The second flag bit usage method is with fully enabled interrupts. When an interrupt flag bit is set and the corresponding interrupt enable bit is also set, the  $\overline{IRQ}$  pin is asserted low.  $\overline{IRQ}$  is asserted as long as at least one of the three interrupt sources has its flag and enable bits both set. The  $IRQF$  bit in Register C is a one whenever the  $\overline{IRQ}$  pin is being driven low. Determination that the RTC initiated an interrupt is accomplished by reading Register C. A logic one in bit 7 ( $IRQF$  bit) indicates that one or more interrupts have been initiated by the DS14285/DS14287. The act of reading Register C clears all active flag bits and the  $IRQF$  bit.

### OSCILLATOR CONTROL BITS

When the DS14287 is shipped from the factory, the internal oscillator is turned off. This feature prevents the lithium energy cell from being used until it is installed in a system. A pattern of 010 in bits 4 through 6 of Register A will turn the oscillator on and enable the countdown chain. A pattern of 11X will turn the oscillator on, but holds the countdown chain of the oscillator in reset. All other combinations of bits 4 through 6 keep the oscillator off.

### SQUARE WAVE OUTPUT SELECTION

Thirteen of the 15 divider taps are made available to a 1-of-15 selector, as shown in the block diagram of Figure 1. The first purpose of selecting a divider tap is to generate a square wave output signal on the SQW pin. The  $RS0$ - $RS3$  bits in Register A establish the square wave output frequency. These frequencies are listed in Table 1. The SQW frequency selection shares its 1-of-15 selector with the periodic interrupt generator. Once the frequency is selected, the output of the SQW pin can be turned on and off under program control with the square wave enable bit ( $SQWE$ ).

### PERIODIC INTERRUPT SELECTION

The periodic interrupt will cause the  $\overline{\text{IRQ}}$  pin to go to an active state from once every 500 ms to once every 122  $\mu\text{s}$ . This function is separate from the alarm interrupt which can be output from once per second to once per day. The periodic interrupt rate is selected using the same Register A bits which select the square wave frequency (see Table 1). Changing the Register A bits affects both the square wave frequency and the periodic interrupt output. However, each function has a separate enable bit in Register B. The SQWE bit controls the square wave output. Similarly, the periodic interrupt is enabled by the PIE bit in Register B. The periodic interrupt can be used with software counters to measure inputs, create output intervals, or await the next needed software function.

### UPDATE CYCLE

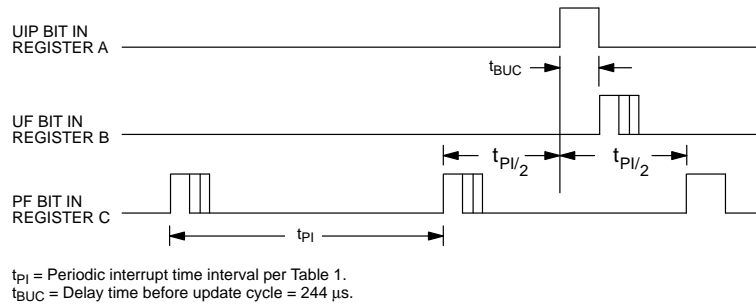
The DS14285/DS14287 executes an update cycle once per second regardless of the SET bit in Register B. When the SET bit in Register B is set to one, the user copy of the double buffered time, calendar, and alarm bytes is frozen and will not update as the time increments. However, the time countdown chain continues to update the internal copy of the buffer. This feature allows time to maintain accuracy independent of reading or writing the time, calendar, and alarm buffers and also guarantees that time and calendar information is consistent. The update cycle also compares each alarm byte with the corresponding time byte and issues an alarm if a match or if a "don't care" code is present in all three positions.

There are three methods that can handle access of the real time clock that avoid any possibility of accessing inconsistent time and calendar data. The first method uses the update-ended interrupt. If enabled, an interrupt occurs after every update cycle that indicates that over 999 ms are available to read valid time and date information. If this interrupt is used, the IRQF bit in Register C should be cleared before leaving the interrupt routine.

A second method uses the update-in-progress bit (UIP) in Register A to determine if the update cycle is in progress. The UIP bit will pulse once per second. After the UIP bit goes high, the update transfer occurs 244  $\mu\text{s}$  later. If a low is read on the UIP bit, the user has at least 244  $\mu\text{s}$  before the time/calendar data will be changed. Therefore, the user should avoid interrupt service routines that would cause the time needed to read valid time/calendar data to exceed 244  $\mu\text{s}$ .

The third method uses a periodic interrupt to determine if an update cycle is in progress. The UIP bit in Register A is set high between the setting of the PF bit in Register C (see Figure 4). Periodic interrupts that occur at a rate of greater than  $t_{\text{BUC}}$  allow valid time and date information to be reached at each occurrence of the periodic interrupt. The reads should be complete within  $1(t_{\text{PI}/2} + t_{\text{BUC}})$  to ensure that data is not read during the update cycle.

### UPDATE-ENDED AND PERIODIC INTERRUPT RELATIONSHIP Figure 4



## REGISTERS

The DS14285/DS14287 has four control registers which are accessible at all times, even during the update cycle.

### REGISTER A

MSB				LSB			
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
UIP	DV2	DV1	DV0	RS3	RS2	RS1	RS0

#### UIP

The Update In Progress (UIP) bit is a status flag that can be monitored. When the UIP bit is a one, the update transfer will soon occur. When UIP is a zero, the update transfer will not occur for at least 244  $\mu$ s. The time, calendar, and alarm information in RAM is fully available for access when the UIP bit is zero. The UIP bit is read only and is not affected by  $\overline{\text{RESET}}$ . Writing the SET bit in Register B to a one inhibits any update transfer and clears the UIP status bit.

#### DV0, DV1, DV2

These three bits are used to turn the oscillator on or off and to reset the countdown chain. A pattern of 010 is the only combination of bits that will turn the oscillator on and allow the RTC to keep time. A pattern of 11X will enable the oscillator but holds the countdown chain in reset. The next update will occur at 500 ms after a pattern of 010 is written to DV0, DV1, and DV2.

#### RS3, RS2, RS1, RS0

These four rate-selection bits select one of the 13 taps on the 15-stage divider or disable the divider output. The tap selected can be used to generate an output square wave (SQW pin) and/or a periodic interrupt. The user can do one of the following:

1. Enable the interrupt with the PIE bit;
2. Enable the SQW output pin with the SQWE bit;
3. Enable both at the same time and the same rate; or
4. Enable neither.

Table 1 lists the periodic interrupt rates and the square wave frequencies that can be chosen with the RS bits. These four read/write bits are not affected by  $\overline{\text{RESET}}$ .

### REGISTER B

MSB				LSB			
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
SET	PIE	AIE	UIE	SQWE	DM	24/12	DSE

#### SET

When the SET bit is a zero, the update transfer functions normally by advancing the counts once per second. When the SET bit is written to a one, any update transfer is inhibited and the program can initialize the time and calendar bytes without an update occurring in the midst of initializing. Read cycles can be executed in a similar manner. SET is a read/write bit that is not modified by  $\overline{\text{RESET}}$  or internal functions of the DS14285/DS14287.

#### PIE

The periodic interrupt enable PIE bit is a read/write bit which allows the Periodic Interrupt Flag (PF) bit in Register C to drive the  $\overline{\text{IRQ}}$  pin low. When the PIE bit is set to one, periodic interrupts are generated by driving the  $\overline{\text{IRQ}}$  pin low at a rate specified by the RS3-RS0 bits of Register A. A zero in the PIE bit blocks the  $\overline{\text{IRQ}}$  output from being driven by a periodic interrupt, but the Periodic Flag (PF) bit is still set at the periodic rate. PIE is not modified by any internal DS14285/DS14287 functions, but is cleared to zero on  $\overline{\text{RESET}}$ .

#### AIE

The Alarm Interrupt Enable (AIE) bit is a read/write bit which, when set to a one, permits the Alarm Flag (AF) bit in register C to assert  $\overline{\text{IRQ}}$ . An alarm interrupt occurs for each second that the three time bytes equal the three alarm bytes including a "don't care" alarm code of binary 11XXXXXX. When the AIE bit is set to zero, the AF bit does not initiate the  $\overline{\text{IRQ}}$  signal. The  $\overline{\text{RESET}}$  pin clears AIE to zero. The internal functions of the DS14285/DS14287 do not affect the AIE bit.

#### UIE

The Update Ended Interrupt Enable (UIE) bit is a read/write that enables the Update End Flag (UF) bit in Register C to assert  $\overline{\text{IRQ}}$ . The  $\overline{\text{RESET}}$  pin going low or the SET bit going high clears to UIE bit.

**SQWE**

When the Square Wave Enable (SQWE) bit is set to a one, a square wave signal at the frequency set by the rate-selection bits RS3 through RS0 is driven out on a SQW pin. When the SQWE bit is set to zero, the SQW pin is held low; the state of SQWE is cleared by the  $\overline{\text{RESET}}$  pin. SQWE is a read/write bit.

**DM**

The Data Mode (DM) bit indicates whether time and calendar information is in binary or BCD format. The DM bit is set by the program to the appropriate format and can be read as required. This bit is not modified by internal functions or  $\overline{\text{RESET}}$ . A one in DM signifies binary data while a zero in DM specifies Binary Coded Decimal (BCD) data.

**24/12**

The 24/12 control bit establishes the format of the hours byte. A one indicates the 24-hour mode and a zero indicates the 12-hour mode. This bit is read/write and is not affected by internal functions of  $\overline{\text{RESET}}$ .

**DSE**

The Daylight Savings Enable (DSE) bit is a read/write bit which enables two special updates when DSE is set to one. On the first Sunday in April the time increments from 1:59:59 AM to 3:00:00 AM. On the last Sunday in October when the time first reaches 1:59:59 AM it changes to 1:00:00 AM. These special updates do not occur when the DSE bit is a zero. This bit is not affected by internal functions or  $\overline{\text{RESET}}$ .

**REGISTER C**

MSB							LSB
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
IRQF	PF	AF	UF	0	0	0	0

**IRQF**

The Interrupt Request Flag (IRQF) bit is set to a one when one or more of the following are true:

PF = PIE = 1

AF = AIE = 1

UF = UIE = 1

That is,  $\text{IRQF} = \text{PF} \bullet \text{PIE} + \text{AF} \bullet \text{AIE} + \text{UF} \bullet \text{UIE}$ .

Any time the IRQF bit is a one, the  $\overline{\text{IRQ}}$  pin is driven low. All flag bits are cleared after Register C is read by the program or when the  $\overline{\text{RESET}}$  pin is low.

**PF**

The Periodic Interrupt Flag (PF) is a read-only bit which is set to a one when an edge is detected on the selected tap of the divider chain. The RS3 through RS0 bits establish the periodic rate. PF is set to a one independent of the state of the PIE bit. When both PF and PIE are ones, the  $\overline{\text{IRQ}}$  signal is active and will set the IRQF bit. The PF bit is cleared by a  $\overline{\text{RESET}}$  or a software read of Register C.

**AF**

A one in the Alarm Interrupt Flag (AF) bit indicates that the current time has matched the alarm time. If the AIE bit is also a one, the  $\overline{\text{IRQ}}$  pin will go low and a one will appear in the IRQF bit. A  $\overline{\text{RESET}}$  or a read of Register C will clear AF.

**UF**

The Update Ended Interrupt Flag (UF) bit is set after each update cycle. When the UIE bit is set to one, the one in UF causes the IRQF bit to be a one which will assert the  $\overline{\text{IRQ}}$  pin. UF is cleared by reading Register C or a  $\overline{\text{RESET}}$ .

**BIT 0 THROUGH BIT 3**

These are unused bits of the status Register C. These bits always read zero and cannot be written.

**REGISTER D**

MSB						LSB	
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
VRT	0	0	0	0	0	0	0

**VRT**

The Valid RAM and Time (VRT) bit indicates the condition of the internal battery (the battery connected to the  $V_{\text{BAT}}$  pin in the case of the DS14285S, DS14285, and the DS14285Q). This bit is not writable and should always be a one when read. If a zero is ever present, an exhausted internal lithium energy source is indicated and both the contents of the RTC data and RAM data are questionable. This bit is unaffected by  $\overline{\text{RESET}}$ .

**BIT 6 THROUGH BIT 0**

The remaining bits of Register D are not usable. They cannot be written and, when read, they will always read zero.

**ABSOLUTE MAXIMUM RATINGS\***

Voltage on Any Pin Relative to Ground	-0.3V to 7.0V
Operating Temperature	0°C to +70°C
Storage Temperature	-40°C to 70°C
Soldering Temperature	260°C for 10 seconds (See Note 12)

\*This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

**RECOMMENDED DC OPERATING CONDITIONS**

(0°C to 70°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Power Supply Voltage	$V_{CC}$	4.5	5.0	5.5	V	1
Input Logic 1	$V_{IH}$	2.2		$V_{CC}+0.3$	V	1
Input Logic 0	$V_{IL}$	-0.3		+0.8	V	1

**DC ELECTRICAL CHARACTERISTICS**(0°C to 70°C;  $V_{CC} = 4.5$  to 5.5V)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Power Supply Current	$I_{CC1}$		7	15	mA	2
Oscillator Current	$I_{OSC}$		300	500	nA	
Input Leakage	$I_{IL}$	-1.0		+1.0	$\mu$ A	3
I/O Leakage	$I_{LO}$	-1.0		+1.0	$\mu$ A	5
MOT Input Current	$I_{MOT}$	-1.0		+500	$\mu$ A	3
$\overline{CEI}$ Input Current	$I_{\overline{CEI}}$	-1.0		200	$\mu$ A	4
$\overline{CEI}$ to $\overline{CEO}$ Impedance	$Z_{CE}$			60	$\Omega$	11
Output @ 2.4V	$I_{OH}$	-1.0			mA	1, 6
Output @ 0.4V	$I_{OL}$			4.0	mA	1
Write Protect Voltage	$V_{TP}$	4.0	4.25	4.5	V	
$V_{CC0}$ Voltage	$V_{CC01}$	$V_{CC}-0.3V$			V	7
$V_{CC0}$ Voltage	$V_{CC02}$	$V_{BAT}-0.3V$			V	8

**CAPACITANCE** $(t_A = 25^\circ\text{C})$ 

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Capacitance	$C_{IN}$			5	pF	
Output Capacitance	$C_{OUT}$			7	pF	

**AC ELECTRICAL CHARACTERISTICS**(0°C to 70°C;  $V_{CC} = 4.5V$  to  $5.5V$ )

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Cycle Time	$t_{CYC}$	225		DC	ns	
Pulse Width, DS/E Low or RD/ $\overline{WR}$ High	$PW_{EL}$	115			ns	
Pulse Width, DS/E High or RD/ $\overline{WR}$ Low	$PW_{EH}$	80			ns	
Input Rise and Fall Time	$t_{R},t_{F}$			30	ns	
$R/\overline{W}$ Hold Time	$t_{RWH}$	10			ns	
$R/\overline{W}$ Setup Time Before DS/E	$t_{RWS}$	10			ns	
Chip Select Setup Time Before DS, WR, or RD	$t_{CS}$	20			ns	
Chip Select Hold Time	$t_{CH}$	0			ns	
Read Data Hold Time	$t_{DHR}$	10		50	ns	
Write Data Hold Time	$t_{DHW}$	0			ns	
Muxed Address Valid Time to AS/ALE Fall	$t_{ASL}$	30			ns	
Muxed Address Hold Time	$t_{AHL}$	10			ns	
Delay Time DS/E to AS/ALE Rise	$t_{ASD}$	20			ns	
Pulse Width AS/ALE High	$PW_{ASH}$	60			ns	
Delay Time, AS/ALE to DS/E Rise	$t_{ASED}$	35			ns	
Output Data Delay Time From DS/E or RD	$t_{DDR}$	10		75	ns	9
Data Setup Time	$t_{DSW}$	60			ns	
Reset Pulse Width	$t_{RWL}$	5			$\mu$ s	
$\overline{IRQ}$ Release from DS	$t_{IRDS}$			2	$\mu$ s	
$\overline{IRQ}$ Release from $\overline{RESET}$	$t_{IRR}$			2	$\mu$ s	

**AC TEST CONDITIONS**

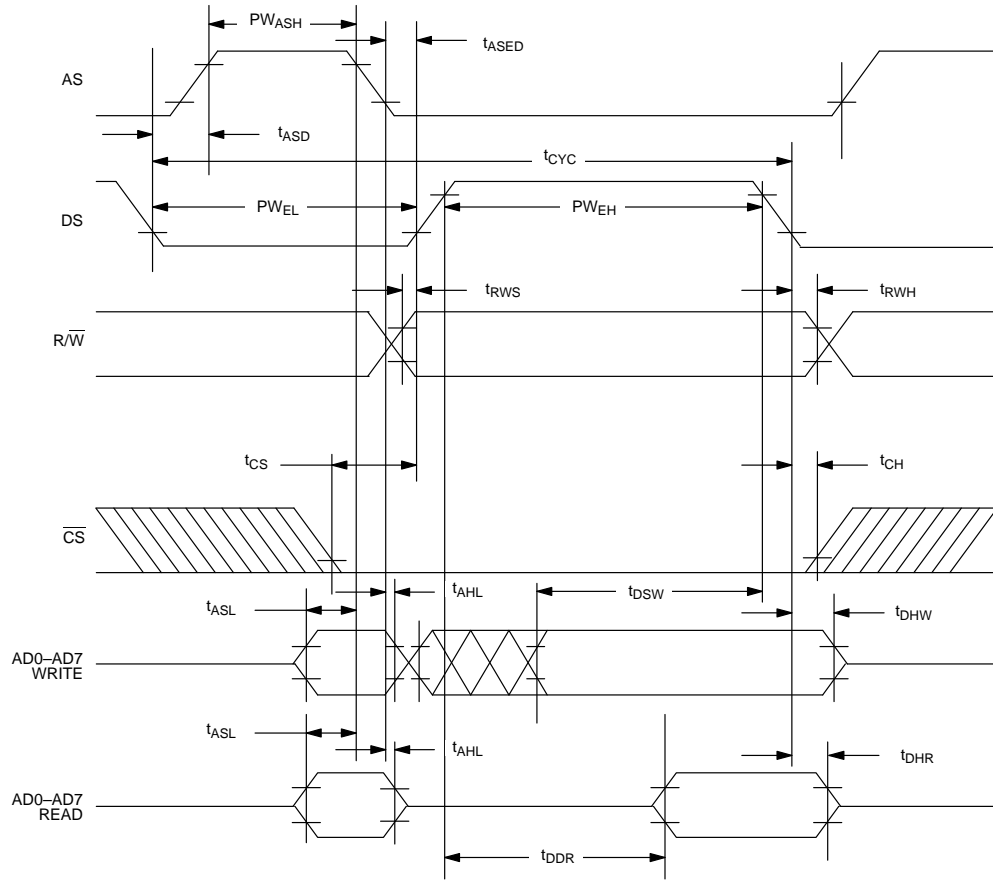
Input Pulse Level: 0 to 3.0V

Input Rise/Fall Times: 5 ns

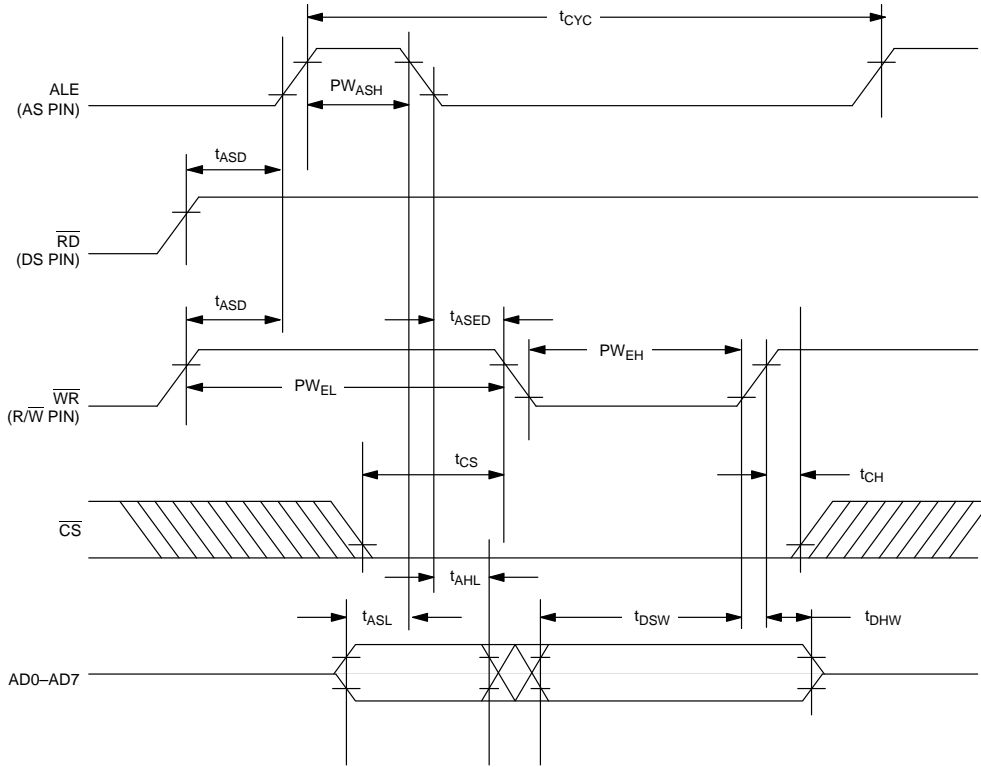
Input and Output Timing Reference Levels: 1.5V

Output Load: Figure 5

**DS14285 BUS TIMING FOR MOTOROLA INTERFACE**

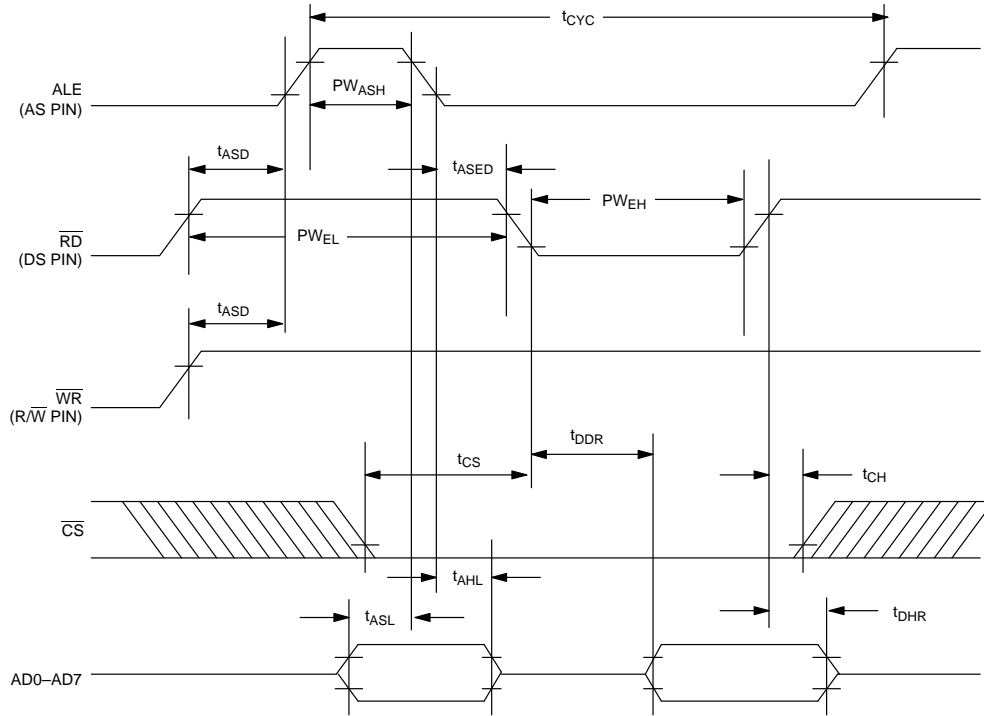


### DS14285/DS14287 BUS TIMING FOR INTEL INTERFACE WRITE CYCLE

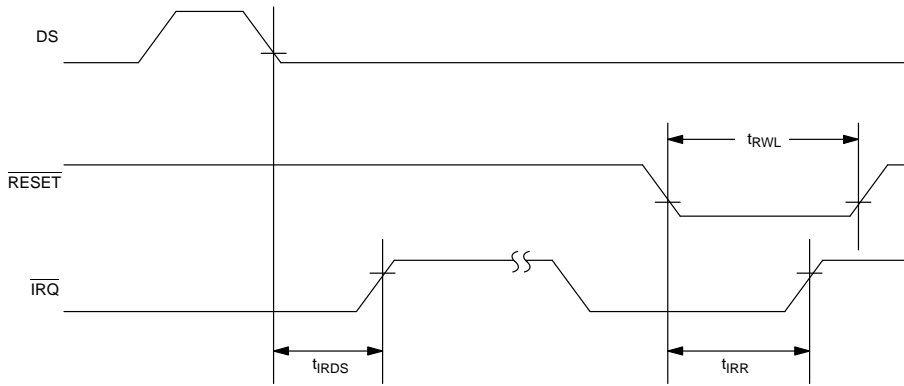




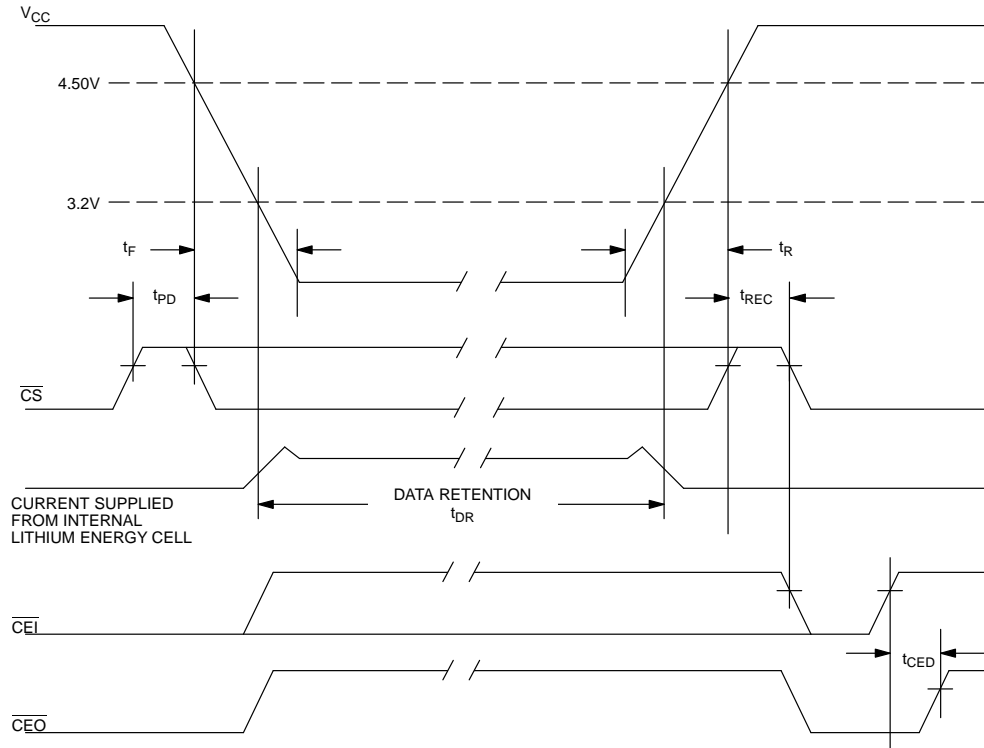
**DS14285/DS14287 BUS TIMING FOR INTEL INTERFACE READ CYCLE**



**DS14285/DS14287 IRQ RELEASE DELAY TIMING**



**POWER DOWN/POWER UP TIMING**



**POWER DOWN/POWER UP TIMING**

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
$\overline{CS}$ at $V_{IH}$ before Power-Down	$t_{PD}$	0			$\mu\text{s}$	
$V_{CC}$ slew from 4.5V to 0V (CS at $V_{IH}$ )	$t_F$	300			$\mu\text{s}$	
$V_{CC}$ slew from 0V to 4.5V (CS at $V_{IH}$ )	$t_R$	100			$\mu\text{s}$	
$\overline{CS}$ at $V_{IH}$ after Power-Up	$t_{REC}$	20		200	ms	
Chip Enable Propagation Delay to External SRAM	$t_{CED}$			10	ns	

( $t_A = 25^\circ\text{C}$ )

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Expected Data Retention for DS14287	$t_{DR}$	10			years	10

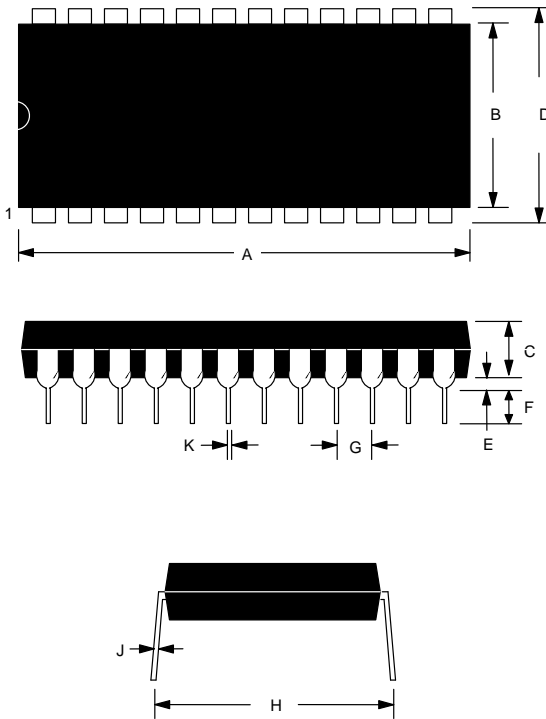
**NOTE:**

The real time clock will keep time to an accuracy of  $\pm 1$  minute per month during data retention time for the period of  $t_{DR}$ .

**WARNING:**

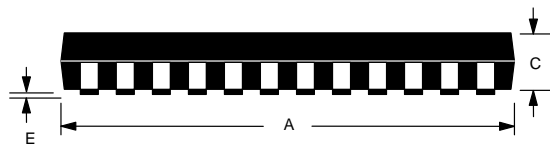
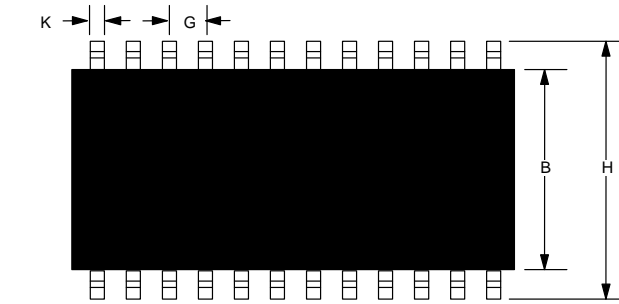
Under no circumstances are negative undershoots, of any amplitude, allowed when device is in battery backup mode.

**DS14285 24-PIN DIP**



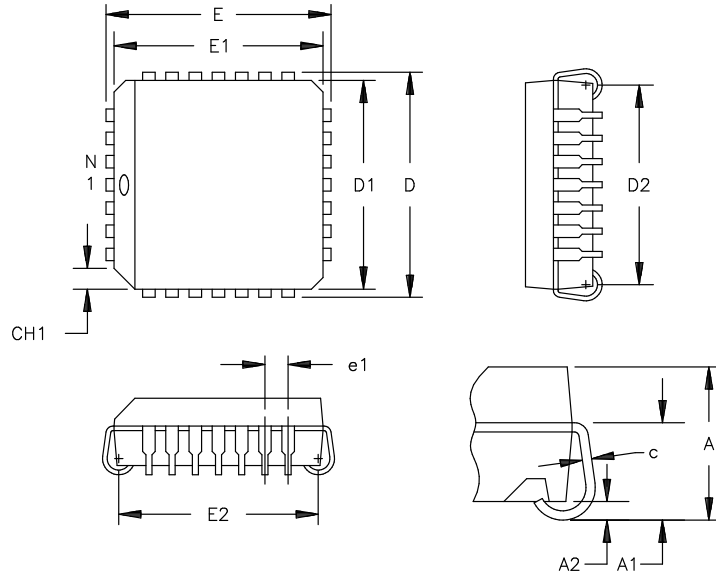
PKG	24-PIN		
	DIM	MIN	MAX
A IN.	1.245	1.270	
MM	31.62	32.25	
B IN.	0.530	0.550	
MM	13.46	13.97	
C IN.	0.140	0.160	
MM	3.56	4.06	
D IN.	0.600	0.625	
MM	15.24	15.88	
E IN.	0.015	0.050	
MM	0.380	1.27	
F IN.	0.120	0.145	
MM	3.05	3.68	
G IN.	0.090	0.110	
MM	2.29	2.79	
H IN.	0.625	0.675	
MM	15.88	17.15	
J IN.	0.008	0.012	
MM	0.20	0.30	
K IN.	0.015	0.022	
MM	0.38	0.559	

**DS14285 24-PIN SOIC**

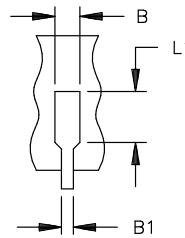


PKG	24-PIN	
DIM	MIN	MAX
A IN. MM	0.602 15.29	0.612 15.54
B IN. MM	0.290 7.37	0.300 7.65
C IN. MM	0.089 2.26	0.095 2.41
E IN. MM	0.004 0.102	0.012 0.30
F IN. MM	0.094 2.38	0.105 2.68
G IN. MM	0.050 BSC 1.27 BSC	
H IN. MM	0.398 10.11	0.416 10.57
J IN. MM	0.009 0.229	0.013 0.33
K IN. MM	0.013 0.33	0.019 0.48
L IN. MM	0.016 0.406	0.040 1.02
phi	0°	8°

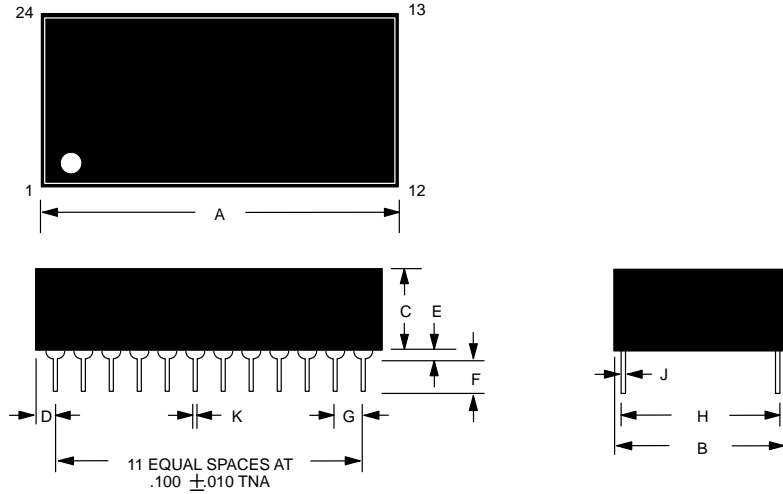
**DS14285Q 28-PIN PLCC**



PKG	28-PIN	
DIM	MIN	MAX
A	0.165	0.180
A1	0.090	0.120
A2	0.020	—
B	0.026	0.033
B1	0.013	0.021
c	0.009	0.012
D	0.485	0.495
D1	0.450	0.456
D2	0.390	0.430
E	0.485	0.495
E1	0.450	0.456
E2	0.390	0.430
L1	0.060	—
N	28	—
e1	0.050 BSC	
CH1	0.042	0.048



**DS14287 REAL TIME CLOCK PLUS RAM**



PKG	24-PIN	
	MIN	MAX
A IN. MM	1.320 33.53	1.335 33.91
B IN. MM	0.720 18.29	0.740 18.80
C IN. MM	0.345 8.76	0.370 9.40
D IN. MM	0.100 2.54	0.130 3.30
E IN. MM	0.015 0.38	0.030 0.76
F IN. MM	0.110 2.79	0.140 3.56
G IN. MM	0.090 2.29	0.110 2.79
H IN. MM	0.590 14.99	0.630 16.00
J IN. MM	0.008 0.20	0.012 0.30
K IN. MM	0.015 0.38	0.021 0.53

NOTE: PINS 2, 3, 16, AND 20 ARE MISSING BY DESIGN.

**NOTES:**

1. All voltages are referenced to ground.
2. All outputs are open.
3. The MOT pin has an internal pulldown of 20 K $\Omega$ .
4. The  $\overline{CEI}$  pin has an internal pull-up of 50K $\Omega$ .
5. Applies to the AD0–AD7 pins, the  $\overline{IRQ}$  pin, and the SQW pin when each is in the high impedance state.
6. The  $\overline{IRQ}$  pin is open drain. The interrupt and the internal clock continue to run regardless of the level of VCC. However, it is important to insure that the pull-up resistor used with the interrupt pin is never pulled up to a value which is greater than VCC + 0.3V. As VCC falls below approximately 3.0 volts, a power switching circuit turns the lithium energy source on to maintain the clock and timer data functionality.
7. I<sub>CCO</sub>=100 mA, V<sub>CC</sub> > V<sub>BAT</sub>.
8. I<sub>CCO</sub>=100  $\mu$ A, V<sub>CC</sub> < V<sub>BAT</sub>.
9. Measured with a load as shown in Figure 5.
10. Expected data retention is based on using an external SRAM with a data retention current of less than 1  $\mu$ A at 25°C.
11. Z<sub>CE</sub> is an average input-to-output impedance as the input is swept from ground to V<sub>CC1</sub> and less than 4 mA is forced through Z<sub>CE</sub>.
12. Real-Time Clock Modules such as the DS14287 can be successfully processed through conventional wave-soldering techniques as long as temperature exposure to the lithium energy source contained within does not exceed +85°C. Post solder cleaning with water washing techniques is acceptable, provided that ultrasonic vibration is not used.

**OUTPUT LOAD Figure 5**